

View Online at <https://aerobasegroup.com/nsn/5961-01-065-9027>

**Inclosure Material:**

Ceramic all transistor and metal all transistor

**Overall Length:**

1.000 inches 4th transistor

**Overall Height:**

0.300 inches 4th transistor

**Overall Width:**

1.000 inches 4th transistor

**Mounting Facility Quantity:**

2 all transistor

**Internal Configuration:**

Junction contact all transistor

**Internal Junction Configuration:**

Npn all transistor

**Component Function Relationship:**

Matched

**Component Name And Quantity:**

4 transistor

**Mounting Method:**

Unthreaded hole all transistor

**Semiconductor Material:**

Silicon all transistor

**Voltage Rating In Volts Per Characteristic:**

35.0 collector to emitter voltage/static/base open 2nd transistor and 60.0 collector to emitter voltage, dc with base short-circuited to emitter 2nd transistor and 4.0 emitter to base voltage, static, collector open 2nd transistor

**Test Data Document:**

87990-755002a0670 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

**Terminal Type And Quantity:**

4 ribbon all transistor

**Shelf Life:**

N/a

**Unit Of Measure:**

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**Demilitarization:**

No

**Fiig:**

A110a0